19-1064: Rev 0: 6/96



Low-Voltage, Dual-Supply, SPST, CMOS Analog Switches

General Description

The MAX4503/MAX4504 are low-voltage, dual-supply, single-pole/single-throw (SPST), CMOS analog switches. The MAX4503 is normally open (NO). The MAX4504 is normally closed (NC).

These CMOS switches can operate continuously with dual supplies between ±1.V and ±6V. Each switch can handle rail-to-rail analog signals. The off-leakage current is only 1nA at +25°C or 10nA at +85°C.

The digital input is CMOS-logic compatible when using ±5V supplies. A unique logic input architecture allows this even though the parts have no ground pin.

For single-supply operation, use the MAX4501/ MAX4502, which are pin-for-pin equivalents.

Applications

Battery-Operated Equipment Audio and Video Signal Routing Low-Voltage Data-Acquisition Systems Communications Circuits Cellular Phones **PCMCIA Cards** Modems

Features

- ♦ Available in SOT23-5 Package
- ♦ Dual-Supply Operation from ±1V to ±6V
- **♦** Guaranteed On-Resistance: 250 Ω with ±5V Supplies
- ♦ Guaranteed Low Off-Leakage Currents: 1nA at +25°C 10nA at +85°C
- ♦ Guaranteed Low On-Leakage Currents: 2nA at +25°C 20nA at +85°C
- Guaranteed Low Charge Injection: 10pC Max
- ◆ Fast Switching Speed: toN = 150ns, toFF = 100ns
- ♦ CMOS-Logic Compatible Input

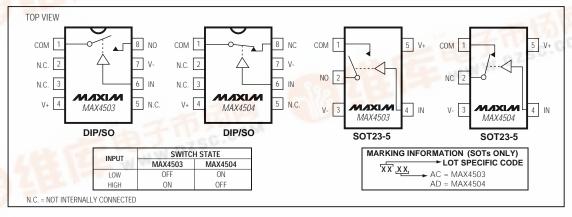
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4503CPA	0°C to +70°C	8 Plastic DIP
MAX4503CSA	0°C to +70°C	8 SO
MAX4503CUK	0°C to +70°C	5 SOT23-5
MAX4503C/D	0°C to +70°C	Dice*
MAX4503EPA	-40°C to +85°C	8 Plastic DIP
MAX4503ESA	-40°C to +85°C	8 SO
MAX4503EUK	-40°C to +85°C	5 SOT23-5
MAX4503MJA	-55°C to +125°C	8 CERDIP**

Ordering Information continued at end of data sheet.

- * Contact factory for dice specifications.
- ** Contact factory for availability

Pin Configurations



Maxim Integrated Products



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ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to V-)	5-Pin S0
V+0.3V, +13V	8-Pin Cl
Voltage into Any Terminal (Note 1)0.3V to (V+ + 0.3V) or	Operating
±10mA (whichever occurs first)	MAX450
Continuous Current into Any Terminal±10mA	MAX450
Peak Current, NO_ or COM_	MAX450
(pulsed at 1ms,10% duty cycle)±20mA	Storage Te
Continuous Power Dissipation ($T_A = +70^{\circ}C$)	Lead Tem
8-Pin Plastic DIP (derate 9.09mW/°C above +70°C)727mW	
8-Pin SO (derate 5.88mW/°C above +70°C)471mW	

5-Pin SOT23-5 (derate 7.1mW/°C ab	
8-Pin CERDIP (derate 8.00mW/°C ab	oove +70°C)640mW
Operating Temperature Ranges	
MAX4503C/MAX4504C	0°C to +70°C
MAX4503E/MAX4504E	40°C to +85°C
MAX4503MJA/MAX4504MJA	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Voltages on any signal terminal exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—±5V Supply

 $(V_+ = +4.5V \text{ to } +5.5V, V_- = -4.5V \text{ to } -5.5V, V_{INH} = 3.5V, V_{INL} = 1.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C.})$

PARAMETER	SYMBOL	CONDITIONS			MIN (TYP Note 2	MAX)	UNITS
ANALOG SWITCH					•			
Analog Signal Range	$\begin{matrix} V_{COM},V_{NO},\\ V_{NC}\end{matrix}$				V-		V+	V
COM to NO or NC	Ron	V _{COM} = 3.5V, I _{COM} = 1mA	T _A = +25°C			60	250	Ω
On-Resistance	KON	VCOM_ = 3.5V, ICOM = IIIIA	$T_A = T_{MIN}$ to	T _{MAX}			350	32
NO 014 - 1		V+ = 5.5V, V- = -5.5V,	$T_{A} = +25^{\circ}C$		-1	0.01	1	
NO or NC Off Leakage Current (Note 3)	INO(OFF), INC(OFF)	$V_{COM_{-}} = \pm 4.5 V$,	TA = TMIN	C, E	-10		10	nA
our on (Note 5)	INC(OFF)	V_{NO} or $V_{NC} = \mp 4.5V$ to T_{MAX}		М	-100		100	
0011071 1 0 1		V+ = 5.5V, V- = -5.5V,	$T_{A} = +25^{\circ}C$		-1	0.01	1	
COM Off Leakage Current (Note 3)	ICOM(OFF)	$V_{COM} = \pm 4.5V$, V_{NO} or $V_{NC} = \mp 4.5V$	T _A = T _{MIN}	C, E	-10		10	nA
(Note 3)			to T _{MAX}	М	-100		100	
		V+ = 5.5V. V- = -5.5V.	T _A = +25°C	•	-2	0.01	2	
COM On Leakage Current (Note 3)	ICOM(ON)	$V_{COM} = \pm 4.5V$,	T _A = T _{MIN}	C, E	-20		20	nA
(Note 3)		V_{NO} or $V_{NC} = \pm 4.5V$	to T _{MAX}	М	-200		200	
DIGITAL I/O								
IN Input Logic High	VIH				(V+) - 1.5		V+	V
IN Input Logic Low	VIL				V-		(V+) - 3.5	V
IN Input Current Logic High or Low	l _{IH} , l _{IL}	V _{IN} = V+, 0V			-1	0.03	1	μΑ

2 ______ *MIXIN*I

ELECTRICAL CHARACTERISTICS—±5V Supply (continued)

 $(V+=+4.5V \text{ to } +5.5V, V-=-4.5V \text{ to } -5.5V, V_{INH}=3.5V, V_{INL}=1.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	MAX	UNITS
SWITCH DYNAMIC CHARA	CTERISTICS						
Turn-On Time	ton	$V_{IN} = 3V$, $R_L = 1k\Omega$	$T_{A} = +25^{\circ}C$		30	150	ns
Turr-On Time	iON	V _{NO} or V _{NC} = 3V, Figure 1	$T_A = T_{MIN}$ to T_{MAX}			240	1115
Turn-Off Time	torr	$V_{IN} = 3V$, $R_L = 1k\Omega$	T _{A =} +25°C		20	100	nc
Turn-On Time	toff	V _{NO} or V _{NC} = 3V, Figure 1	TA = TMIN to TMAX			150	ns
Charge Injection (Note 4)	Q	$C_L = 1$ nF, $V_{NO} = 0$ V, $R_S = 0$ Ω , $T_{A} = +25$ °C, Figure 2			1	10	рС
Off Isolation	V _{ISO}	$R_L = 50\Omega$, $C_L = 15pF$, $V_{NO} = 1V_{RMS}$, $f = 100kHz$, $T_{A} = +25^{\circ}C$, Figure 3			<-90		dB
NO or NC Off Capacitance	CNO(OFF)	f = 1MHz, T _{A = +25°C} , Figure	4		3		рF
COM Off Capacitance	Coff(COM)	$f = 1MHz$, $T_{A = +25^{\circ}C}$, Figure	4		3		рF
COM On Capacitance	C _{ON} (COM)	$f = 1MHz$, $T_{A = +25^{\circ}C}$, Figure 4			9		рF
POWER SUPPLY							•
V+, V- Supply Current	l+, l-	V _{IN} = 0V or V+	T _A = +25°C	-125	40	125	
v+, v- supply culterit	1+, 1-	$V_{IN} = 0V OI V + T_{A} = T_{MIN} \text{ to } T$		-200		200	μA

ELECTRICAL CHARACTERISTICS—±3V Supply

 $(V+=+2.7V \text{ to } +3.3V, V-=-2.7V \text{ to } -3.3V, V_{INH}=2.4V, V_{INL}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A=+25^{\circ}\text{C.}$)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2	MAX	UNITS
ANALOG SWITCH				'				
Analog Signal Range	V _{COM} , V _{NO} ,				0		V+	V
COM to NO or NC	Ron	V _{COM} = 1.5V, I _{COM} = 0.1mA	T _A = +25°C	,		100	400	Ω
On-Resistance	KON	VCOM_ = 1.5V, ICOM = 0.1111A	$T_A = T_{MIN} t$	o T _{MAX}			500	32
NO NC Off I I	1	$V_{COM} = \pm 1.5V$	$T_{A} = +25^{\circ}C$		-1		1	
NO or NC Off Leakage Current (Notes 3, 4)	INO(OFF), INC(OFF)	V_{NO} or $V_{NC} = \mp 1.5V$,	TA = TMIN	C, E	-10		10	nA
	110(011)	$V + = 3.3V$, $V - = -3.3V$ to T_{MAX}	to T _{MAX}	М	-100		100	
COM Off Landson Comment		$V_{COM} = \pm 1.5V$	$T_{A} = +25^{\circ}C$		-1		1	
COM Off Leakage Current (Notes 3, 4)	ICOM(OFF)	$V_{NO} \text{ or } V_{NC} = \mp 1.5V,$ $V_{+} = 3.3V, V_{-} = -3.3V$	$T_{A} = T_{MIN}$ to T_{MAX}	C, E	-10		10	nA
(110100 0) 1)				М	-100		100	
00110		V_{NO} or $V_{NC} = \pm 1.5V$,	T _A = +25°C	:	-2		2	
COM On Leakage Current (Notes 3, 4)	ICOM(ON)	$V_{COM} = \pm 1.5V$	$T_{A} = T_{MIN}$	C, E	-20		20	nA
(110100 07 17		V+ = 3.3V, V- = -3.3V	to T _{MAX}	М	-200		200	
DIGITAL I/O								
IN Input Logic High	V _{INH}				2.4		V+	V
IN Input Logic Low	VINL				V-		(V+) - 2.3	V
IN Input Current Logic High or Low	I _{IH} , I _{IL}				-1	0.03	1	μA
POWER SUPPLY		1						•
V+, V- Supply Current	l+, l-	IN = 0V or V+	T _{A =} +25°C		-100	25	100	
v+, v- Supply Culterit	1+, 1-	IIN = UV UI V+	T _A = T _{MIN} to	xAMT c	-175		175	μΑ

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

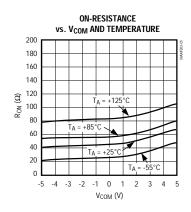
Note 4: Guaranteed, not production tested.

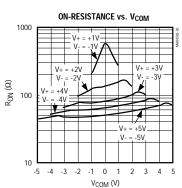
Note 3: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at +25°C.

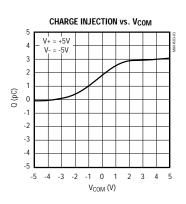
Note 5: SOT packaged parts are 100% tested at +25°C. Limits at maximum and minimum rated temperature are guaranteed by design and correlation limits at +25°C.

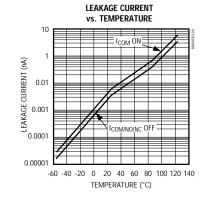
Typical Operating Characteristics

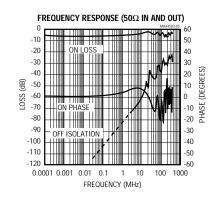
 $(V+ = +5V, V- = -5V, T_A = +25$ °C, unless otherwise noted.)

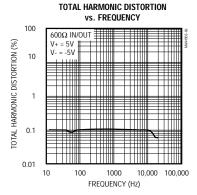


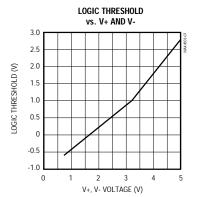












Pin Description

	Р	IN					
MAX4503		MAX4504		K4503 MA		NAME	FUNCTION
DIP/SO	SOT23-5	DIP/SO	SOT23-5				
1	1	1	1	COM	Analog Switch Common Terminal		
2, 3, 5	=	2, 3, 5	=	N.C.	No Connect (not internally connected)		
4	5	4	5	V+	Positive (analog and digital) Supply Voltage Input		
6	4	6	4	IN	Digital Control Input		
7	3	7	3	V-	Negative (analog) Supply Voltage Input		
8	2	-	-	NO	Analog Switch Normally Open Terminal		
-	=	8	2	NC	Analog Switch Normally Closed Terminal		

Note: NO, NC, and COM pins are identical and interchangeable. Either may be considered as an input or output; signals pass equally well in both directions.

_Applications Information

Power-Supply Considerations

The MAX4503/MAX4504's construction is typical of most CMOS analog switches, except they have only two supply pins: V+ and V-. These voltages set the analog voltage limits of the switch. Reverse ESD-protection diodes are internally connected between IN and each analog signal pin and both V+ and V-. If any analog signal exceeds V+ or V-, one of these diodes will conduct. During normal operation, these (and other) reverse-biased ESD diodes leak, forming the only current drawn from V-. Additional current flows through V+ from the logic-level translator.

Virtually all the analog leakage current is provided through the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V+ and V-pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

There is no connection between the analog signal paths and V+ or V-.

 $\mbox{V+}$ and $\mbox{V-}$ also power the internal logic and logic-level translators. Since there is no ground pin, the logic input

has a low-current pull-up to V+ and the logic limit is set by an internal comparator referenced to V+. The logiclevel translators convert the logic levels to switched V+ and V- signals, to drive the gates of the analog signals. This drive signal is the only connection between the logic supplies (and signals) and the analog supplies. COM, NO, and NC pins have ESD-protection diodes to V+ and V-.

The logic is CMOS compatible when V+ is +5V. CMOS compatibility is maintained with all V+ values, assuming that the CMOS logic is operated from the same V+ supply. Since the MAX4503/MAX4504 have no ground pins, the logic levels are internally referenced to V+.

Do not connect the MAX4503/MAX4504 V+ to +3V and connect the logic-level pins to TTL-logic-level signals. TTL levels can exceed +3V and violate the absolute maximum ratings, damaging the part and/or external circuits.

High-Frequency Performance In 50Ω systems, signal response is reasonably flat up to 50MHz. (see *Typical Operating Characteristics*). Above 20MHz the on-response has several minor peaks which are highly layout dependent. The problem is not in turning the switch on, but in turning it off. The off-state switch acts like a capacitor, and passes higher frequencies with less attenuation. At 10MHz, off isolation is about -65dB in 50Ω systems, becoming worse (approximately 20dB per decade) as frequency

increases. Higher circuit impedances also make off iso-

lation worse.

Test Circuits/Timing Diagrams

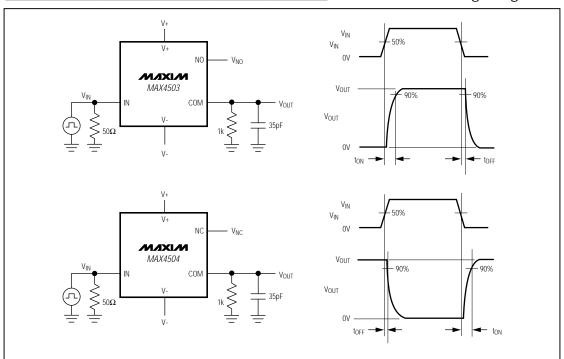


Figure 1. Switching Times

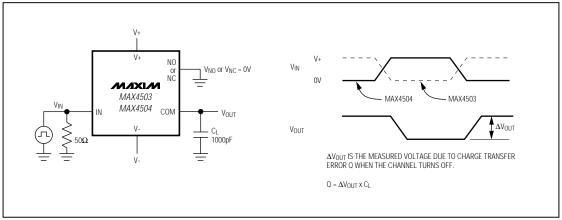


Figure 2. Charge Injection

Test Circuits/Timing Diagrams (continued)

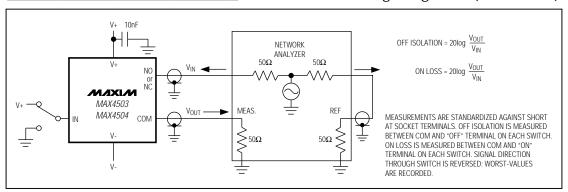


Figure 3. Off Isolation and On Loss

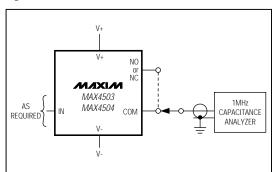


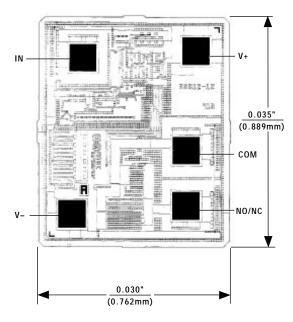
Figure 4. NO, NC, and COM Capacitance

_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE	
MAX4504CPA	0°C to +70°C	8 Plastic DIP	
MAX4504CSA	0°C to +70°C	8 SO	
MAX4504CUK	0°C to +70°C	5 SOT23-5	
MAX4504C/D	0°C to +70°C	Dice*	
MAX4504EPA	-40°C to +85°C	8 Plastic DIP	
MAX4504ESA	-40°C to +85°C	8 SO	
MAX4504EUK	-40°C to +85°C	5 SOT23-5	
MAX4504MJA	-55°C to +125°C	8 CERDIP**	

^{*} Contact factory for dice specifications.

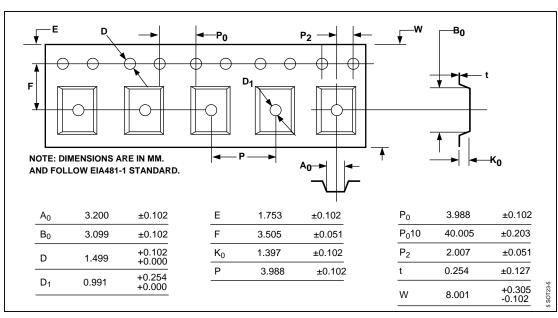
_Chip Topography

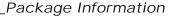


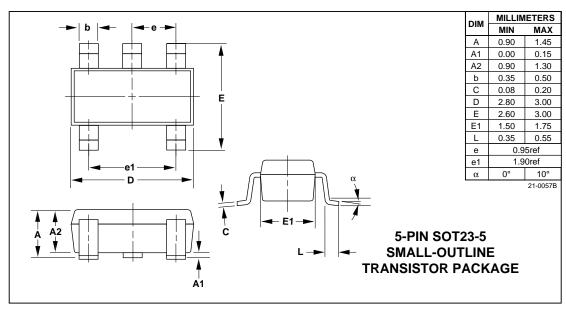
TRANSISTOR COUNT: 36
SUBSTRATE IS INTERNALLY CONNECTED TO V+

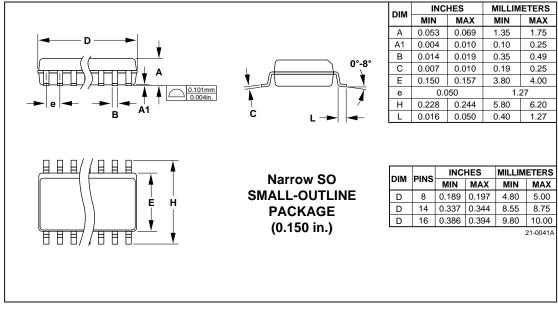
^{**} Contact factory for availability.

_Tape-and-Reel Information

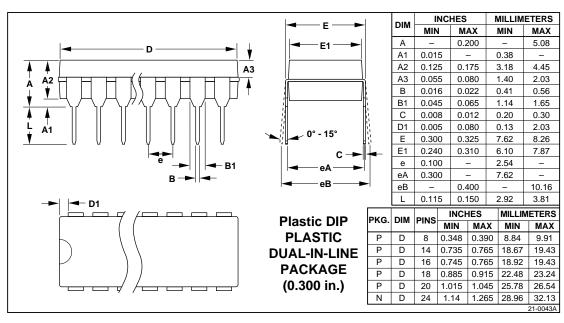




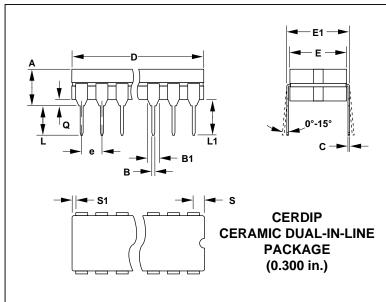




Package Information (continued)



Package Information (continued)



ым	INC	HES	MILLIM	ETERS
DIIWI	MIN	MAX	MIN	MAX
Α	-	0.200	-	5.08
В	0.014	0.023	0.36	0.58
B1	0.038	0.065	0.97	1.65
С	0.008	0.015	0.20	0.38
Е	0.220	0.310	5.59	7.87
E1	0.290	0.320	7.37	8.13
е	0.1	0.100		54
L	0.125	0.200	3.18	5.08
L1	0.150	_	3.81	_
Q	0.015	0.070	0.38	1.78
S	_	0.098	_	2.49
S1	0.005	_	0.13	_

		1110			TETEDO.	
ЫΜ	PINS	_	HES		METERS	
		MIN	MAX	MIN	MAX	
D	8	-	0.405	_	10.29	
D	14	-	0.785	_	19.94	
D	16	-	0.840	_	21.34	
D	18	-	0.960	_	24.38	
D	20	-	1.060	_	26.92	
D	24	_	1.280	-	32.51	
21 00454						

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